NSN 5961-01-353-5533

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-5533 **Inclosure Material:** Ceramic or plastic or metal **Overall Length:** 90.0 millimeters **Overall Height:** 30.0 millimeters **Overall Width:** 20.0 millimeters **Mounting Facility Quantity: Component Name And Quantity:** 1 semiconductor device thyristor and 1 semiconductor device diode **Mounting Method:** Unthreaded hole Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage single semiconductor device thyristor800.0 repetitive peak reverse voltage single semiconductor device diode **Current Rating Per Characteristic:** 51.00 amperes drain current universal single semiconductor device diode **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure:** Demilitarization: No